

International Application No.: PCT/JP2005/11260

U.S. Patent Application No.: Unknown

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AMENDMENTS TO THE SPECIFICATION:

A substitute specification and a marked-up copy of the English translation of the originally filed PCT application are attached hereto.

Please replace the Title of the Invention originally filed with the above-identified patent application with the following new Title:

SEMICONDUCTOR DEVICE HAVING HIGH-K GATE DIELECTRIC LAYER
AND METHOD FOR MANUFACTURING THE SAME